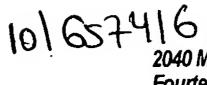
Knobbe Martens Olson & Bear LLP

Intellectual Property Law



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Katsuhiro Arai *
Japanese Patent Attorney
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1/

December 7, 2006

Certificate

DEC 1 4 2006

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

of Correction

Re:

Title: INTER LAYER INSULATION FILM USED FOR MULTILAYER

INTERCONNECT OF SEMICONDUCTOR INTEGRATED CIRCUIT AND

METHOD OF MANUFACTURING THE SAME

Letters Patent No. 7,098,129 Issued: August 29, 2006

Our Reference: ASMJP.134AUS

Dear Sir:

Enclosed for filing is a Certificate of Correction in connection with the above-identified patent.

As the errors cited in the Certificate of Correction were incurred through the fault of the Applicant, enclosed is our check in the amount of \$100. Please charge any additional fees to our Deposit Account No. 11-1410.

Respectfully submitted,

12/12/2006 JBALINAN 00000047 7098129

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100.00 OP

Knobbe, Martens, Olson & Bear, LLP

Katsuhiro Arai

Registration No. 43,315 Customer No. 20,995

Enclosures

3168842 120106 DEG 1 5 2005

UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO.

: 7,098,129

Page 1 of 2

APPLICATION NO.

: 10/657,416

ISSUE DATE

: August 29, 2006

INVENTOR(S)

: Naoto TSUJI, Fumitoshi OZAKI, Satoshi TAKAHASHI

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the first page, at Column 2 (Other Publications), please delete "Sysmposium" and insert -- Symposium --, therefor.

On the first page, at Column 2 (Other Publications), please delete "Technology," and insert -- Technology,--, therefor.

At Column 3, line 11, after "may be," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane --, therefor.

• At Column 10, line 41-42, after "DM-DMOS," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 11, line 11, after "DM-DMOS," please delete "dimethy-dimethoxysilane" and insert --dimethyl-dimethoxysilane,-- therefor.

At Column 13, line 37-38, after "hydrocarbon is," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 13, line 63, after "hydrocarbon is," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 15, line 10, after "the second gas is," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 5, line 9, after "wherein," please delete "a" and insert -- α --, therefor.

At Column 5, line 66, after "C₆H₅," please delete "C₃H₅, C₃H₅," and insert -- C₃H₅,--, therefor.

At Column 8, line 11, after "such as 1.5," please delete "W/Cm²" and insert -- W/cm² --, therefor.

MAILING ADDRESS OF SENDER:

Katsuhiro Arai KNOBBE, MARTENS, OLSON & BEAR, LLP 2040 Main Street, 14th Floor Irvine, California 92614

DOCKET NO. ASMJP.134AUS

DEC 1 5 2006"

UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO.

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Page 2 of 2

APPLICATION NO.

: 10/657,416

ISSUE DATE

: August 29, 2006

INVENTOR(S)

: Naoto TSUJI, Fumitoshi OZAKI, Satoshi TAKAHASHI

At Column 9, line 18, after "become," please delete "unstablilized." And insert -- unstabilized.-- therefor.

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